









	SI4178DY-T1-E3
	Hersteller-Teilenummer: SI4178DY-T1-E3
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET N-CH 30V 12A 8SO
	Datenblätter:  SI4178DY-T1-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
Lagerzustand: New original, 55041 pcs Stock Available.	Liefern von: Hong Kong
Image may be representation. See specs for product details.	Versandweg: DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	SI4178DY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 12A 8SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	55041 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	2.4W (Ta), 5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	21 mOhm @ 8.4A, 10V
VGS (th) (Max) @ Id	2.8V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	405pF @ 15V
Verpackung	Tape & Reel (TR)



















































SI4178DY-T1-E3 ist neu im Original, Suche SI4178DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4178DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4178DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4178DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 12A 8-SOIC</p>	 <p>SI4178 VISHAY SI4178 VISHAY</p>	 <p>SI4186DY-T1-E3 Vishay Precision Group SI4186DY-T1-E3 VISHAY</p>	 <p>SI4178DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 12A 8SO</p>
 <p>SI4178DY-TI-GE3 VISHAY VISHAY SOP8</p>	 <p>SI4176DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 12A 8-SOIC</p>	 <p>SI4178DY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 12A 8-SOIC</p>	 <p>SI4186DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 35.8A 8SOIC</p>

heiße Teile

Mehr

 SI4164DY-T1-E3	 SI4164DY-T1-GE3	 SI4164DY-T1-GE3	 SI4166DY	 SI4166DY-T1-E3
 SI4166DY-T1-GE3	 SI4166DY-T1-GE3	 SI4168DY	 SI4168DY-T1-E3	 SI4168DY-T1-GE3
 SI4168DY-T1-GE3	 SI4170DY-T1-GE3	 SI4170DY-T1-GE3	 SI4172DY	 SI4172DY-T1-E3
 SI4172DY-T1-GE3	 SI4172DY-T1-GE3	 SI4174DY	 SI4174DY-T1-E3	 SI4174DY-T1-GE3
 SI4174DY-T1-GE3	 SI4176DY-T1-GE3	 SI4176DY-T1-GE3	 SI4178DY	 SI4178DY-T1-E3
 SI4178DY-T1-GE3	 SI4178DY-T1-GE3	 SI4186DY-T1-E3	 SI4188DY-T1-E3	 SI4190ADY
 SI4196DY-T1-GE3	 SI4196DY-T1-GE3	 SI4200-BM	 SI4200-BMR	 SI4200-GM
 SI4200-GMR	 SI4200BM	 SI4200DB-BMR	 SI4200DY-T1-E3	 SI4201-BMR
 SI4201-GMR	 SI4202DY	 SI4205-BM	 SI4205-BMR	 SI4206-BM
 SI4206-BMR	 SI4208-A-GMR	 SI4208GM	 SI4209-A-GMR	 SI4210-C-GMR

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